S/N 10/809,033

3 N THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

SASAKI et al.

Serial No .:

10/809,033

Filed:

March 25, 2004

Docket No.:

10873.1440US01

Title:

METHOD OF MANUFACTURING GROUP III NITRIDE SINGLE CRYSTAL, DEVICE USED FOR THE METHOD AND GROUP III NITRIDE SINGLE CRYSTAL OBTAINED BY THE METHOD

CERTIFICATE UNDER 37 CFR 1.10:

"Express Mail" mailing label number: EV 407260607 US

Date of Deposit: August 4, 2004

I hereby certify that this paper or fee is being deposited with the U.S. Postal Service "Express Mail Post Office to Addressee" service under 37 CFR 1.10 on the date indicated above and is addressed to Commissioner for Patents, Mail Stop MISSING PARTS, P.O. Box 1450, Alexandria, VA 22313-1450.

INFORMATION DISCLOSURE STATEMENT (37 C.F.R. § 1.97(b))

Mail Stop MISSING PARTS

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

With regard to the above-identified application, the items of information listed on the enclosed Form 1449 are brought to the attention of the Examiner.

This statement should be considered because it is submitted within three months of the filing date of the above-identified application, which is not an application under 37 C.F.R. § 1.53(d). Accordingly, no fee is due for consideration of the items listed on the enclosed Form 1449.

In accordance with 37 C.F.R. §1.98(a)(2), a copy of each document or other information listed on the enclosed Form 1449 is provided.

No representation is made that a reference is "prior art" within the meaning of 35 U.S.C. §§ 102 and 103 and Applicants reserve the right, pursuant to 37 C.F.R. § 1.131 or otherwise, to establish that the reference(s) are not "prior art." Moreover, Applicants do not represent that a

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reference has been thoroughly reviewed or that any relevance of any portion of a reference is intended.

Consideration of the items listed is respectfully requested. Pursuant to the provisions of M.P.E.P. 609, it is requested that the Examiner return a copy of the attached Form 1449, marked as being considered and initialed by the Examiner, to the undersigned with the next official communication.

Please charge any additional fees or credit any overpayment to Deposit Account No. 13-2725.

Respectfully submitted,

MERCHANT & GOULD P.C. P.O. Box 2903 Minneapolis, MN 55402-0903 (612) 332-5300

Dated: August 4, 2004

By: Douglas P. Mueller

Reg. No. 30,300

DPM/jh

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FORM 1449* Proposition disclosure statement	Docket Number: Application Number: 10873.1440US01 10/809,033		
S IN AN APPLICATION	Applicant: SASAKI et al.	_	
AUG 0 4 2004 (Use several sheets if necessary)	Filing Date: March 25, 2004	Group Art Unit: Unknown	

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	2000-233993		08.2000	Japan			Abstract	
77.70								
		OTHER	DOCUMENT	S (Including Author, Title, I	Date, Pertinent P	'ages, Etc.)		
		Kurai et al., "Nucleation Control in the Growth of Bulk GaN by Submission Method", Jpn. J. Appl. Phys., Vol. 36 (1997), pp. L184-L186, Part 2, No. 2B, 15 February 1997						
		Nishino et al., "Bulk GaN Growth by Direct Synthesis Method", Journal of Crystal Growth, 237-239 (2002) 922-925.						
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23552 PATENT TRADEMARK OFFICE

EXAMINER	DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.